





# NPN PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR

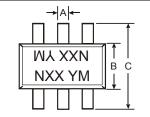
#### **Features**

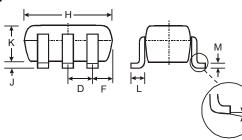
- **Epitaxial Planar Die Construction**
- Complementary PNP Types Available (DDA)
- **Built-In Biasing Resistors**
- Lead Free/RoHS Compliant (Note 3)
- "Green" Device (Note 4 and 5)

# **Mechanical Data**

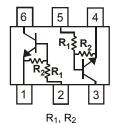
- Case: SOT-363
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Matte Tin Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Terminal Connections: See Diagram
- Marking Information: See Diagrams & Page 3
- Ordering Information: See Page 3
- Weight: 0.006 grams (approximate)

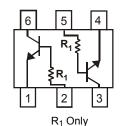
P/N	R1 (NOM)	R2 (NOM)	MARKING
DDC122LU	0.22K	10K	N81
DDC142JU	0.47K	10K	N82
DDC122TU	0.22K	OPEN	N83
DDC142TU	0.47K	OPEN	N84





	SOT-363									
Dim	Min	Max								
Α	0.10	0.30								
В	1.15	1.35								
С	2.00	2.20								
D	0.65 Nominal									
F	0.30	0.40								
Н	1.80	2.20								
J	_	0.10								
K	0.90	1.00								
L	0.25	0.40								
M	0.10	0.25								
α	0°	8°								
All Din	nensions	in mm								





SCHEMATIC DIAGRAM

#### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic		Symbol	Value	Unit
Supply Voltage (6) to (1) and (3) to (4)		$V_{CC}$	50	V
Input Voltage (2) to (1) and (5) to (4)	DDC122LU DDC142JU	Vini	-5 to +6 -5 to +6	V
Input Voltage (1) to (2) and (4) to (5)	DDC122TU DDC142TU	V <sub>EBO (MAX)</sub>	5	V
Output Current	All	Ic	100	mA
Power Dissipation	(Note 1)	$P_d$	200	mW
Thermal Resistance, Junction to Ambient Air	(Note 2)	$R_{ hetaJA}$	625	°C/W

Notes:

- 150mW per element must not be exceeded.
- Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead.
- Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com/products/lead free/index.php.
- Product manufactured with Date Code UO (week 40, 2007) and newer are built with Green Molding Compound. Product manufactured prior to Date Code UO are built with Non-Green Molding Compound and may contain Halogens or Sb2O3 Fire Retardants.

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# Electrical Characteristics @TA = 25°C unless otherwise specified R1, R2 Types

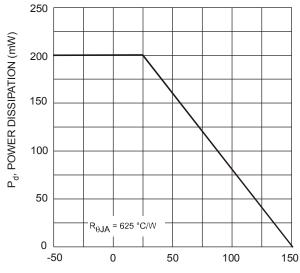
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Input Voltage	DDC122LU DDC142JU	V <sub>I(off)</sub>	0.3 0.3	_	_	٧	$V_{CC}$ = 5V, $I_{O}$ = 100 $\mu$ A
	DDC122LU DDC142JU	V <sub>I(on)</sub>	2.0 2.0		٧	$V_O = 0.3V$ , $I_O = 20mA$ $V_O = 0.3V$ , $I_O = 20mA$	
Output Voltage		V <sub>O(on)</sub>		_	0.3V	V	$I_{O}/I_{I} = 5mA/0.25mA$
Input Current	DDC122LU DDC142JU	I <sub>I</sub>	_	_	28 13	mA	V <sub>I</sub> = 5V
Output Current		I <sub>O(off)</sub>	_	_	0.5	μА	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V
DC Current Gain	DDC122LU DDC142JU	Gı	56 56	_	_	_	V <sub>O</sub> = 5V, I <sub>O</sub> = 10mA
Gain-Bandwidth Product*		f <sub>T</sub>		200	_	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = 5mA, f = 100MHz

<sup>\*</sup> Transistor - For Reference Only

# Electrical Characteristics @TA = 25°C unless otherwise specified R1- Only

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	50	_	_	V	$I_C = 50\mu A$	
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	40	_	_	V	I <sub>C</sub> = 1mA	
Emitter-Base Breakdown Voltage DDC122TU DDC142TU		BV <sub>EBO</sub>	5		—	٧	$I_E = 50 \mu A$ $I_E = 50 \mu A$
Collector Cutoff Current		I <sub>CBO</sub>			0.5	μА	V <sub>CB</sub> = 50V
Emitter Cutoff Current	DDC122TU DDC142TU	I <sub>EBO</sub>			0.5 0.5	μА	V <sub>EB</sub> = 4V
Collector-Emitter Saturation Voltage		V <sub>CE(sat)</sub>	_	_	0.3	V	I <sub>C</sub> = 5mA, I <sub>B</sub> = 0.25mA
DC Current Transfer Ratio DDC122TU DDC142TU		h <sub>FE</sub>	100 100	250 250	600 600		I <sub>C</sub> = 1mA, V <sub>CE</sub> = 5V
Gain-Bandwidth Product*		f⊤		200	_	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz

<sup>\*</sup> Transistor - For Reference Only



T<sub>A</sub>, AMBIENT TEMPERATURE (°C) Fig. 1 Power Derating Curve

(150mW per element must not be exceeded).

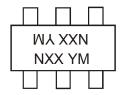


### Ordering Information (Note 6)

Device	Packaging	Shipping
DDC122LU-7-F	SOT-363	3000/Tape & Reel
DDC142JU-7-F	SOT-363	3000/Tape & Reel
DDC122TU-7-F	SOT-363	3000/Tape & Reel
DDC142TU-7-F	SOT-363	3000/Tape & Reel

Notes: 6. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

## **Marking Information**



NXX = Product Type Marking Code See Page 1 Diagrams YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	Ν	Р	R	S	Т	C	٧	W	Х	Y	Z

Ī	Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
	Code	1	2	3	4	5	6	7	8	9	0	N	D

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